## NSN 5962-01-077-2849

Memory Microcircuit - Page 1 of 1



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Body Length:
Between 0.640 inches and 0.795 inches
Body Width:
Between 0.220 inches and 0.310 inches
Body Height:
Between 0.140 inches and 0.205 inches
Maximum Power Dissipation Rating:
400.0 milliwatts
Operating Tempurature Range:
-65.0/+150.0 degrees celsius
Storage Tempurature Range:
-65.0/+200.0 degrees celsius
Features Provided:
Hermetically sealed and monolithic and positive outputs and programmable and medium speed
Inclosure Material:
Ceramic and glass
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Current-mode logic
Input Circuit Pattern:
8 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
35.0 volts power source
Time Rating Per Chacteristic:
25.00 nanoseconds propagation delay time, low to high level output
Memory Device Type:
Diode matrix
Test Data Document:
26916-058-002081 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing
etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Terminal Type And Quantity:
14 printed circuit
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:

Fiig:

A458a0

Yes - demil/mli